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Spec No: 38-05256

Spec Title: CY7C1061AV33, 16-MBIT (1M X 16) STATIC RAM

Replaced by: None

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CY7C1061AV33

16-Mbit (1M × 16) Static RAM

Features

- High speed
  - t_{AA} = 10 ns
- Low active power
  - 990 mW (max)
- Operating voltages of 3.3 ± 0.3 V
- 2.0 V data retention
- Automatic power down when deselected
- TTL compatible inputs and outputs
- Easy memory expansion with $\overline{CE}_1$ and CE_2 features
- Available in Pb-free and non Pb-free 54-pin TSOP II package and non Pb-free 60-ball fine-pitch ball grid array (FBGA) package

Functional Description

The CY7C1061AV33 is a high performance CMOS Static RAM organized as 1,048,576 words by 16 bits.

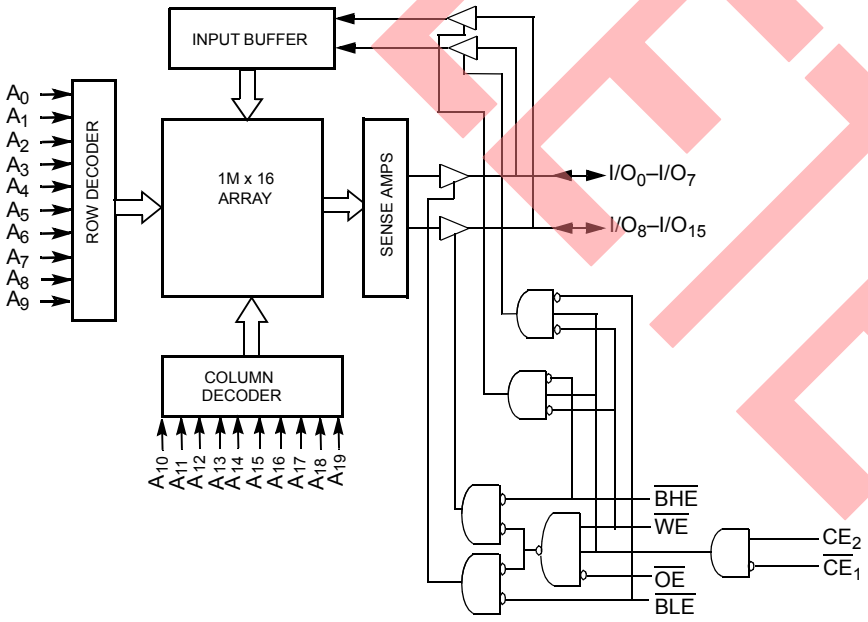
To write to the device, enable the chip ($\overline{CE}_1$ LOW and CE_2 HIGH) while forcing the Write Enable ($\overline{WE}$) input LOW. If Byte Low Enable ($\overline{BLE}$) is LOW, then data from I/O pins (I/O_0 through I/O_7), is written into the location specified on the address pins (A_0 through A_{19}). If Byte High Enable ($\overline{BHE}$) is LOW, then data from I/O pins (I/O_8 through I/O_{15}) is written into the location specified on the address pins (A_0 through A_{19}).

To read from the device, enable the chip by taking $\overline{CE}_1$ LOW and CE_2 HIGH while forcing the Output Enable ($\overline{OE}$) LOW and the Write Enable ($\overline{WE}$) HIGH. If Byte Low Enable ($\overline{BLE}$) is LOW, then data from the memory location specified by the address pins will appear on I/O_0 to I/O_7. If Byte High Enable ($\overline{BHE}$) is LOW, then data from memory will appear on I/O_8 to I/O_{15}. See Truth Table on page 11 for a complete description of Read and Write modes.

The input/output pins (I/O_0 through I/O_{15}) are placed in a high-impedance state when the device is deselected ($\overline{CE}_1$ HIGH/CE_2 LOW), the outputs are disabled ($\overline{OE}$ HIGH), the $\overline{BHE}$ and $\overline{BLE}$ are disabled ($\overline{BHE}$, $\overline{BLE}$ HIGH), or a Write operation is in progress ($\overline{CE}_1$ LOW, CE_2 HIGH, and $\overline{WE}$ LOW).

For a complete list of related documentation, click here.

Logic Block Diagram



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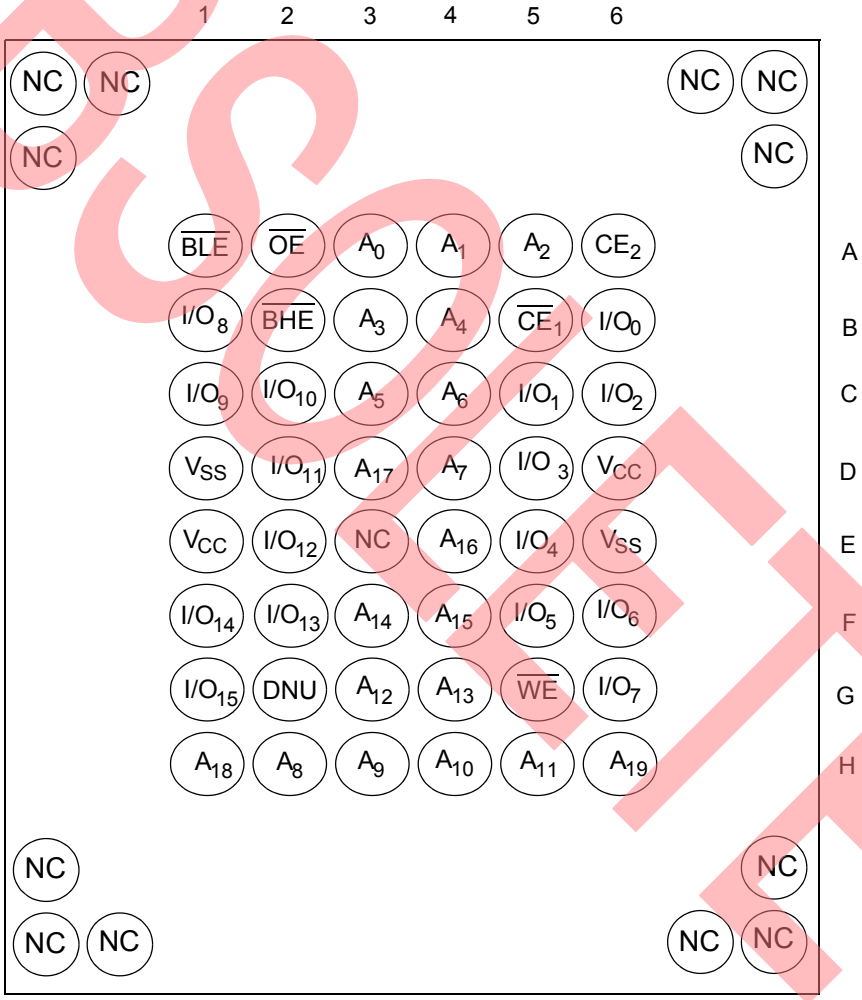
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Selection Guide

Description		-10	Unit
Maximum Access Time		10	ns
Maximum Operating Current	Commercial	275	mA
	Industrial	275	
Maximum CMOS Standby Current	Commercial / Industrial	50	mA

Pin Configurations

Figure 1. 60-ball FBGA pinout (Top View) [1, 2]



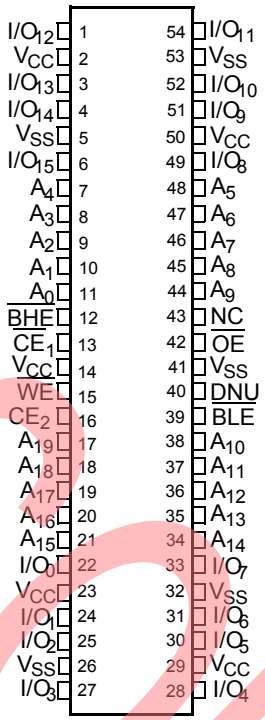
Notes
1. NC pins are not connected on the die.
2. DNU (Do Not Use) pins have to be left floating or tied to VSS to ensure proper operation.

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Pin Configurations (continued)

Figure 2. 54-pin TSOP II pinout (Top View) [3, 4]



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Notes
3. NC pins are not connected on the die.
4. DNU (Do Not Use) pins have to be left floating or tied to VSS to ensure proper operation.

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Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. These user guidelines are not tested.

Storage Temperature ..... –65 °C to +150 °C

Ambient Temperature with Power Applied ..... –55 °C to +125 °C

Supply Voltage on V_{CC} to Relative GND [5] .....–0.5 V to +4.6 V

DC Voltage Applied to Outputs in High Z State [5] ..... –0.5 V to V_{CC} + 0.5 V

DC Input Voltage [5] ..... –0.5 V to V_{CC} + 0.5 V

Current into Outputs (LOW) ..... 20 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0 °C to +70 °C	3.3 V ± 0.3 V
Industrial	–40 °C to +85 °C	

DC Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions		-10		Unit
				Min	Max	
V_{OH}	Output HIGH Voltage	I_{OH} = –4.0 mA		2.4	–	V
V_{OL}	Output LOW Voltage	I_{OL} = 8.0 mA		–	0.4	V
V_{IH}	Input HIGH Voltage			2.0	V_{CC} + 0.3	V
V_{IL}	Input LOW Voltage [5]			–0.3	0.8	V
I_{IX}	Input Leakage Current	GND ≤ V_I ≤ V_{CC}		–1	+1	µA
I_{OZ}	Output Leakage Current	GND ≤ V_O ≤ V_{CC}, Output Disabled		–1	+1	µA
I_{CC}	V_{CC} Operating Supply Current	V_{CC} = max, f = f_{max} = $1/t_{RC}$	Commercial	–	275	mA
			Industrial	–	275	mA
I_{SB1}	Automatic CE Power-down Current – TTL Inputs	CE_2 ≤ V_{IL}, Max V_{CC}, $\overline{CE}$ ≥ V_{IH}, V_{IN} ≥ V_{IH} or V_{IN} ≤ V_{IL}, f = f_{max}		–	70	mA
I_{SB2}	Automatic CE Power-down Current – CMOS Inputs	CE_2 ≤ 0.3 V, Max V_{CC}, $\overline{CE}$ ≥ V_{CC} – 0.3 V, V_{IN} ≥ V_{CC} – 0.3 V, or V_{IN} ≤ 0.3 V, f = 0	Commercial / Industrial	–	50	mA

Note

5. V_{IL}(min) = –2.0 V for pulse durations of less than 20 ns.

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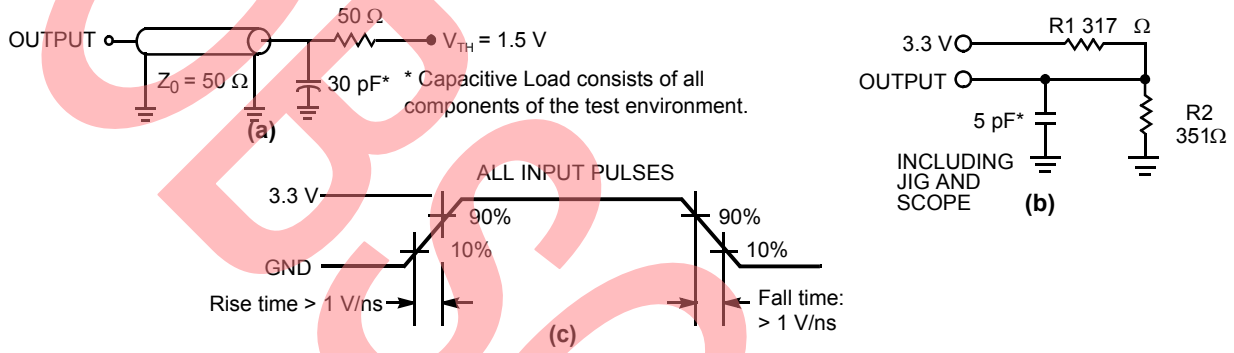
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Capacitance

Parameter [6]	Description	Test Conditions	TSOP II	FBGA	Unit
C_{IN}	Input capacitance	T_A = 25 °C, f = 1 MHz, V_{CC} = 3.3 V	6	8	pF
C_{OUT}	I/O capacitance		8	10	pF

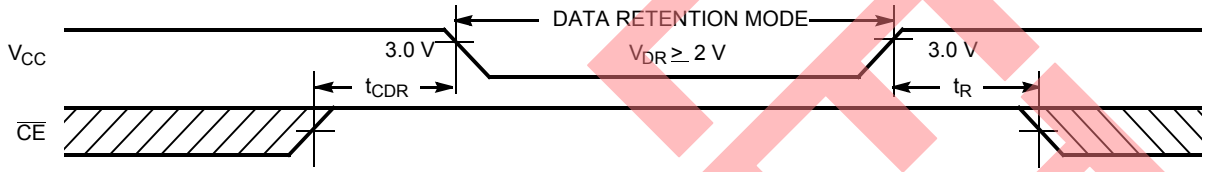
AC Test Loads and Waveforms

Figure 3. AC Test Loads and Waveforms [7]



Data Retention Waveform

Figure 4. Data Retention Waveform



Notes
6. Tested initially and after any design or process changes that may affect these parameters.
7. Valid SRAM operation does not occur until the power supplies have reached the minimum operating V_{DD} (3.0 V). As soon as 1 ms (T_{power}) after reaching the minimum operating V_{DD}, normal SRAM operation can begin including reduction in V_{DD} to the data retention (V_{CCDR}, 2.0 V) voltage.

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AC Switching Characteristics

Over the Operating Range

Parameter [8]	Description	-10		Unit
		Min	Max	
Read Cycle				
t_{power}	V_{CC}(typical) to the first access [9]	1	–	ms
t_{RC}	Read Cycle Time	10	–	ns
t_{AA}	Address to Data Valid	–	10	ns
t_{OHA}	Data Hold from Address Change	3	–	ns
t_{ACE}	$\overline{CE}_1$ LOW/CE_2 HIGH to Data Valid	–	10	ns
t_{DOE}	$\overline{OE}$ LOW to Data Valid	–	5	ns
t_{LZOE}	$\overline{OE}$ LOW to Low Z	1	–	ns
t_{HZOE}	$\overline{OE}$ HIGH to High Z [10]	–	5	ns
t_{LZCE}	$\overline{CE}_1$ LOW/CE_2 HIGH to Low Z [10]	3	–	ns
t_{HZCE}	$\overline{CE}_1$ HIGH/CE_2 LOW to High Z [10]	–	5	ns
t_{PU}	$\overline{CE}_1$ LOW/CE_2 HIGH to Power Up [11]	0	–	ns
t_{PD}	$\overline{CE}_1$ HIGH/CE_2 LOW to Power Down [11]	–	10	ns
t_{DBE}	Byte Enable to Data Valid	–	5	ns
t_{LZBE}	Byte Enable to Low Z	1	–	ns
t_{HZBE}	Byte Disable to High Z	–	5	ns
Write Cycle [12, 13]				
t_{WC}	Write Cycle Time	10	–	ns
t_{SCE}	$\overline{CE}_1$ LOW/CE_2 HIGH to Write End	7	–	ns
t_{AW}	Address Setup to Write End	7	–	ns
t_{HA}	Address Hold from Write End	0	–	ns
t_{SA}	Address Setup to Write Start	0	–	ns
t_{PWE}	$\overline{WE}$ Pulse Width	7	–	ns
t_{SD}	Data Setup to Write End	5.5	–	ns
t_{HD}	Data Hold from Write End	0	–	ns
t_{LZWE}	$\overline{WE}$ HIGH to Low Z [10]	3	–	ns
t_{HZWE}	$\overline{WE}$ LOW to High Z [10]	–	5	ns
t_{BW}	Byte Enable to End of Write	7	–	ns

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Notes

8. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and specified transmission line loads. Test conditions for the Read cycle use output loading shown in (a) of the Figure 3 on page 6, unless specified otherwise.
9. This part has a voltage regulator that steps down the voltage from 3 V to 2 V internally. t_{power} time must be provided initially before a Read/Write operation is started.
10. t_{HZOE}, t_{HZCE}, t_{HZWE}, t_{HZBE} and t_{LZOE}, t_{LZCE}, t_{LZWE}, t_{LZBE} are specified with a load capacitance of 5 pF as in (b) of Figure 3 on page 6. Transition is measured ±200 mV from steady-state voltage.
11. These parameters are guaranteed by design and are not tested.
12. The internal Write time of the memory is defined by the overlap of $\overline{CE}_1$ LOW (CE_2 HIGH) and $\overline{WE}$ LOW. Chip enables must be active and $\overline{WE}$ and byte enables must be LOW to initiate a Write, and the transition of any of these signals can terminate the Write. The input data setup and hold timing should be referenced to the leading edge of the signal that terminates the Write.
13. The minimum Write cycle time for Write Cycle No. 2 ($\overline{WE}$ controlled, $\overline{OE}$ LOW) should be equal to the sum of t_{SD} and t_{HZWE}.

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Switching Waveforms

Figure 5. Read Cycle No. 1 (Address Transition Controlled) [14, 15]

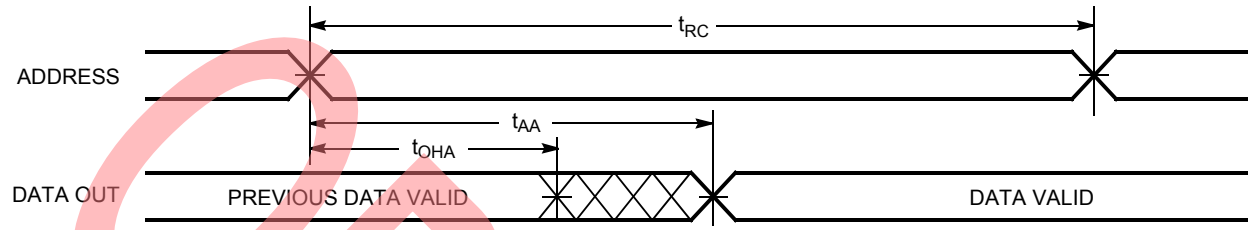
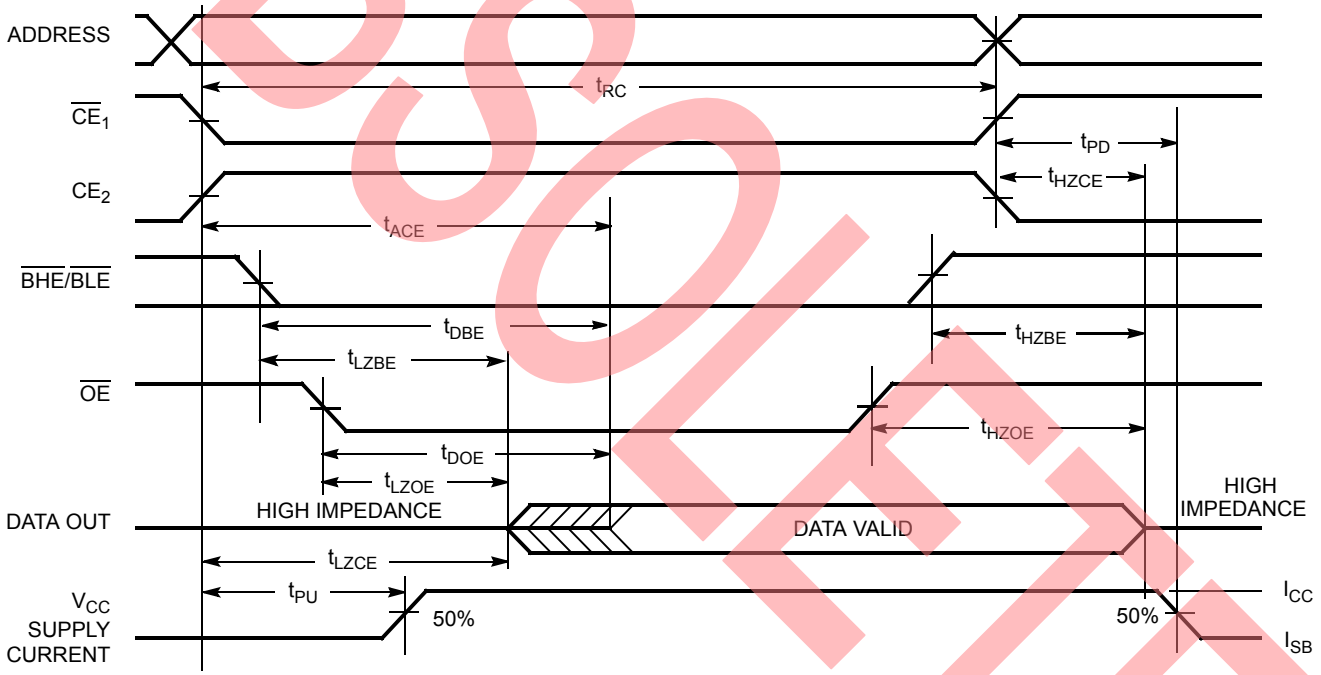


Figure 6. Read Cycle No. 2 ($\overline{OE}$ Controlled) [15, 16]



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Notes
14. Device is continuously selected. $\overline{OE}$, $\overline{CE}$, $\overline{BHE}$ or $\overline{BHE}$, or both = V_{IL}. CE_2 = V_{IH}.
15. $\overline{WE}$ is HIGH for Read cycle.
16. Address valid prior to or coincident with $\overline{CE}_1$ transition LOW and CE_2 transition HIGH.

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Switching Waveforms (continued)

Figure 7. Write Cycle No. 1 ($\overline{CE_1}$ or CE_2 Controlled) [17, 18]

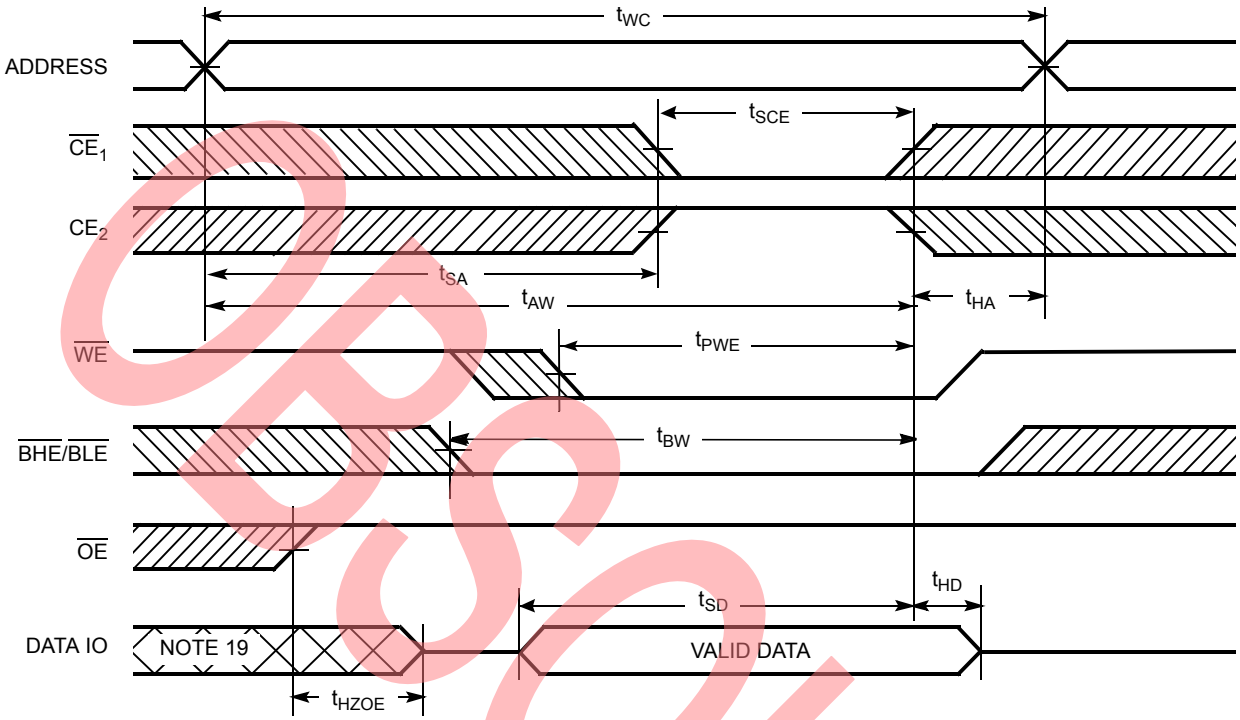
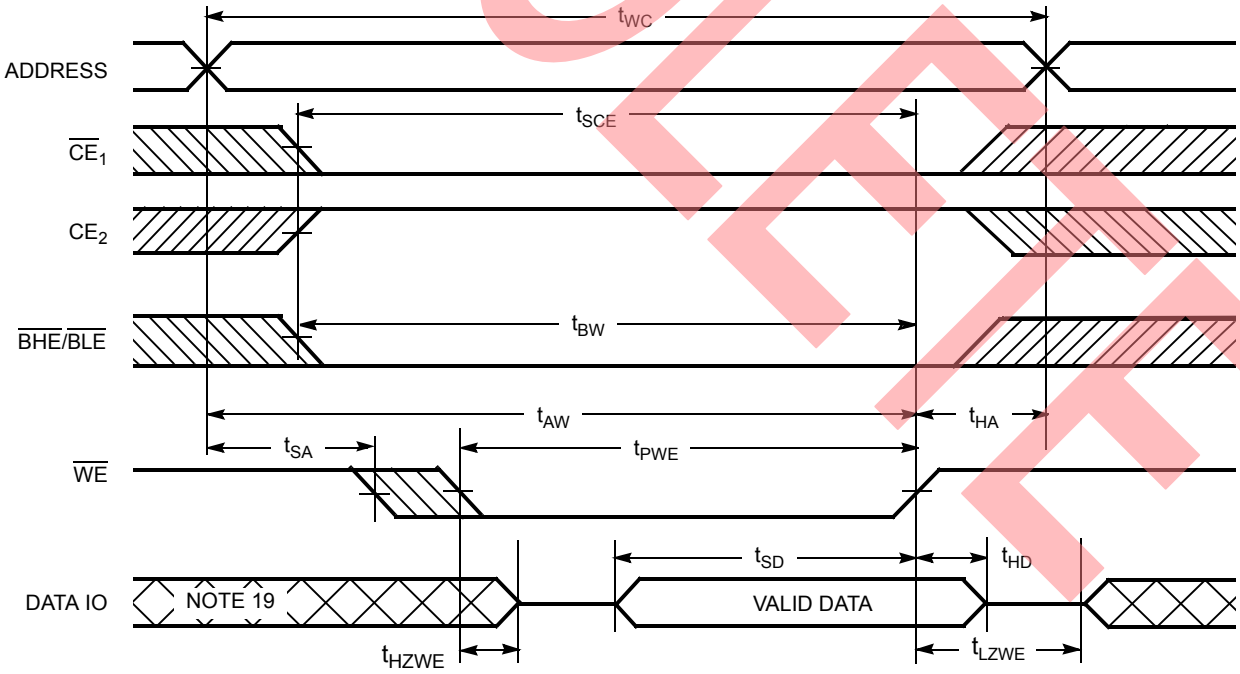


Figure 8. Write Cycle No. 2 ($\overline{WE}$ Controlled, $\overline{OE}$ LOW) [17, 18, 20]



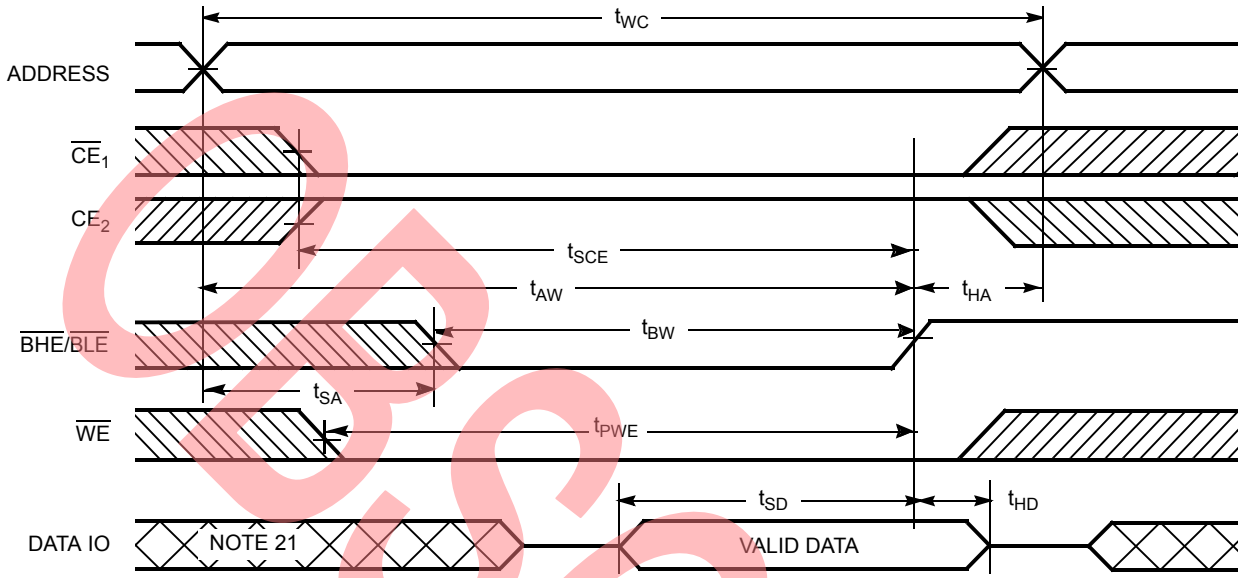
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Notes
17. Data IO is high impedance if $\overline{OE}$, or $\overline{BHE}$ or $\overline{BLE}$ or both = V_{IH}.
18. If $\overline{CE_1}$ goes HIGH simultaneously with $\overline{WE}$ going HIGH, the output remains in a high impedance state.
19. During this period, the IOs are in output state and input signals should not be applied.
20. The minimum write cycle pulse width should be equal to the sum of t_{SD} and t_{HZWE}.

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Switching Waveforms (continued)

Figure 9. Write Cycle No. 3 ($\overline{BHE}$/$\overline{BLE}$ Controlled)



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Note
21. During this period, the IOs are in output state and input signals should not be applied.

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Truth Table

$\overline{CE}_1$	CE_2	$\overline{OE}$	$\overline{WE}$	$\overline{BLE}$	$\overline{BHE}$	I/O_0–I/O_7	I/O_8–I/O_{15}	Mode	Power
H	X	X	X	X	X	High Z	High Z	Power Down	Standby (I_{SB})
X	L	X	X	X	X	High Z	High Z	Power Down	Standby (I_{SB})
L	H	L	H	L	L	Data Out	Data Out	Read All Bits	Active (I_{CC})
L	H	L	H	L	H	Data Out	High Z	Read Lower Bits Only	Active (I_{CC})
L	H	L	H	H	L	High Z	Data Out	Read Upper Bits Only	Active (I_{CC})
L	H	X	L	L	L	Data In	Data In	Write All Bits	Active (I_{CC})
L	H	X	L	L	H	Data In	High Z	Write Lower Bits Only	Active (I_{CC})
L	H	X	L	H	L	High Z	Data In	Write Upper Bits Only	Active (I_{CC})
L	H	H	H	X	X	High Z	High Z	Selected, Outputs Disabled	Active (I_{CC})

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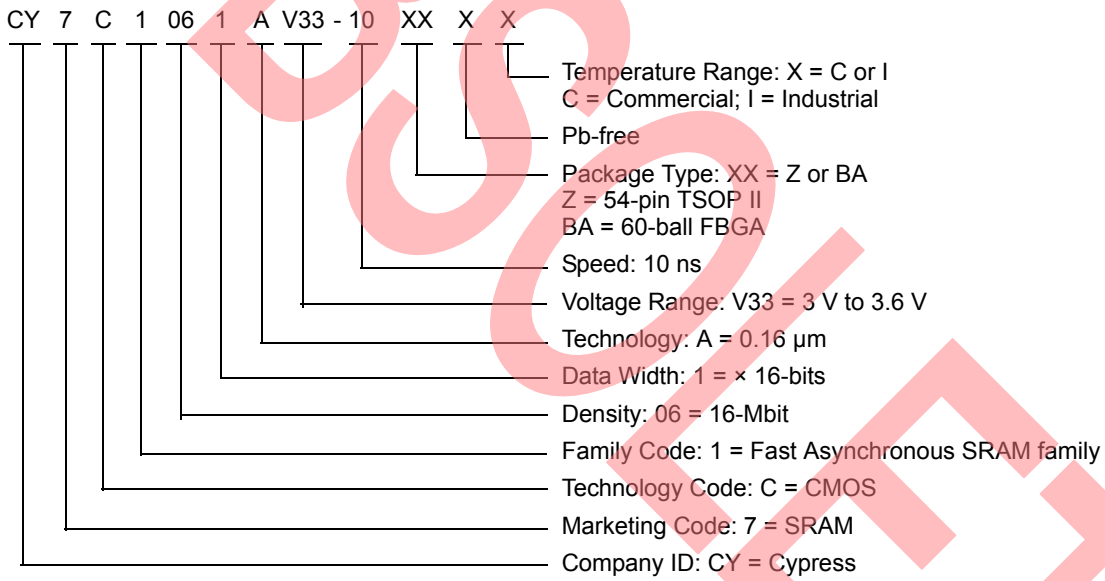
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Ordering Information

The following table lists the CY7C1061AV33 key package features and ordering codes. The table contains only the parts that are currently available. If you do not see what you are looking for, contact your local sales representative. For more information, visit the Cypress website at www.cypress.com and refer to the product summary page at http://www.cypress.com/products.

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
10	CY7C1061AV33-10ZXC	51-85160	54-pin TSOP II (Pb-free)	Commercial
	CY7C1061AV33-10ZXI	51-85160	54-pin TSOP II (Pb-free)	Industrial
	CY7C1061AV33-10BAXI	51-85162	60-ball FBGA (Pb-free)	

Ordering Code Definitions

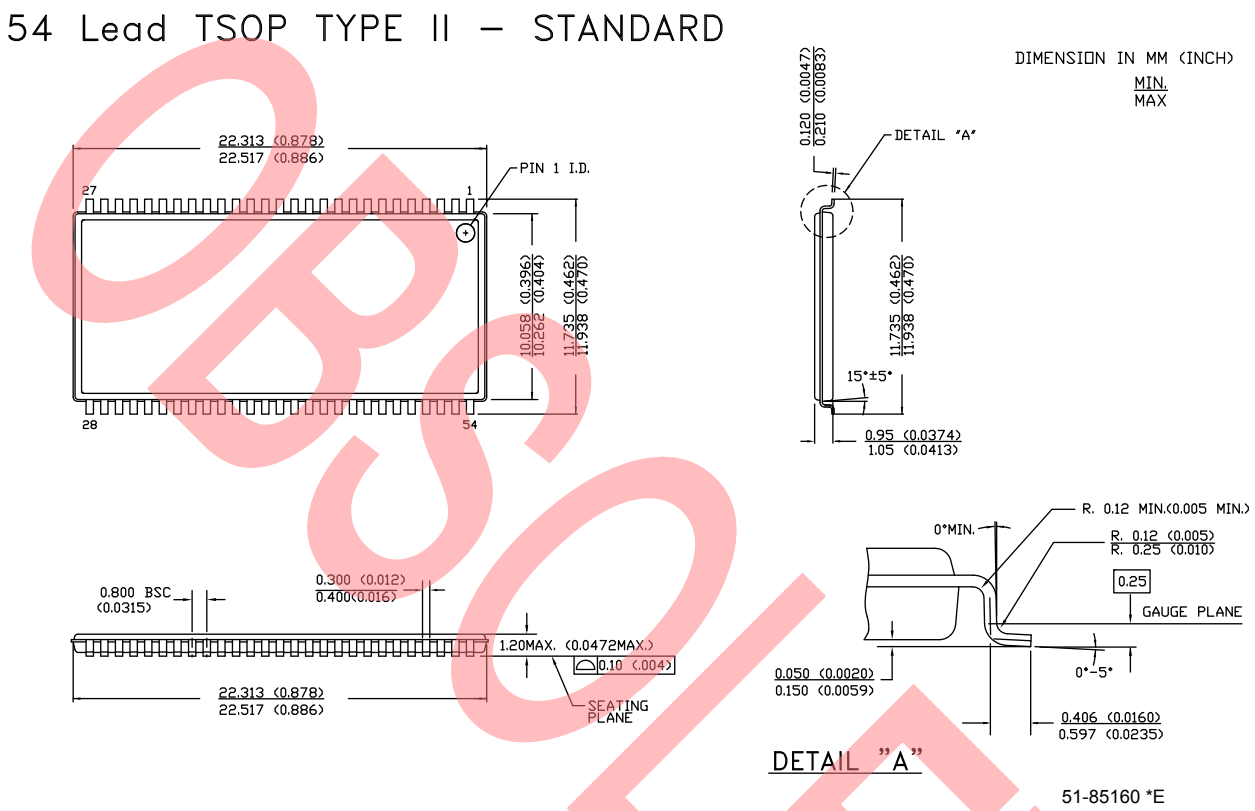


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Package Diagrams

Figure 10. 54-pin TSOP II (22.4 × 11.84 × 1.0 mm) Package Outline, 51-85160

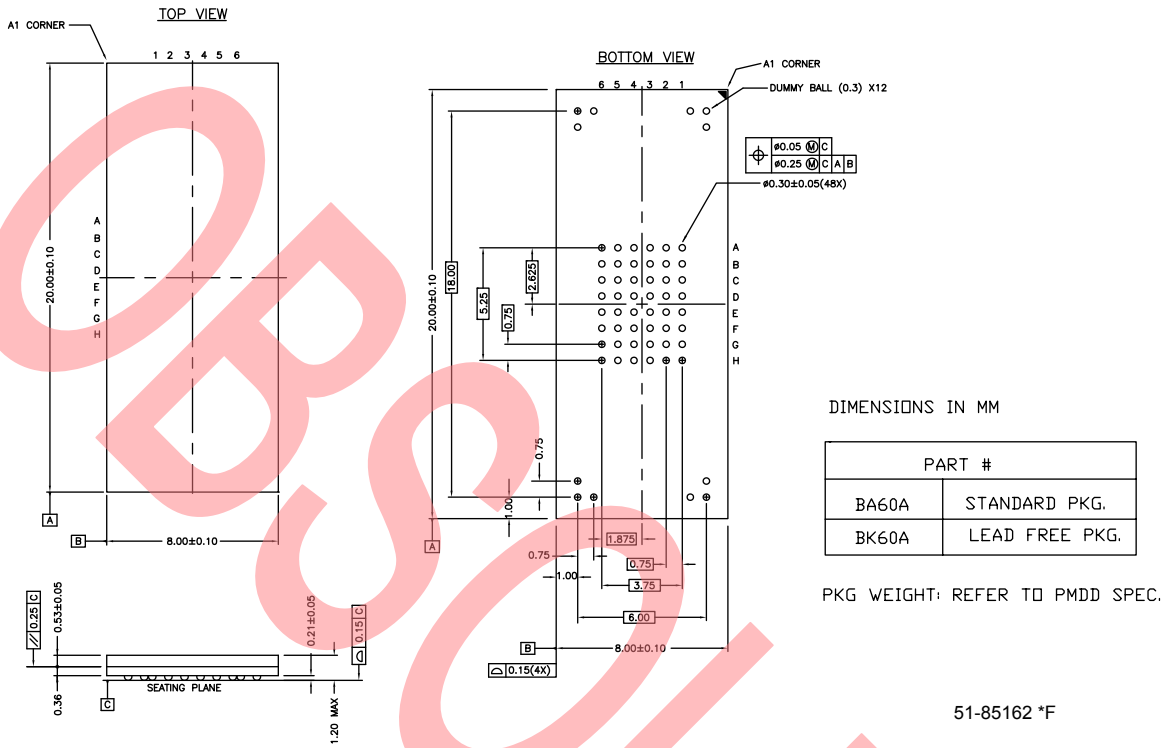


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Package Diagrams (continued)

Figure 11. 60-ball FBGA (8 × 20 × 1.2 mm) Package Outline, 51-85162



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Acronyms

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
FBGA	Fine-Pitch Ball Grid Array
I/O	Input/Output
$\overline{OE}$	Output Enable
SRAM	Static Random Access Memory
TSOP	Thin Small-Outline Package
TTL	Transistor-Transistor Logic
$\overline{WE}$	Write Enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
MHz	megahertz
µA	microampere
mA	milliampere
mm	millimeter
ms	millisecond
mW	milliwatt
ns	nanosecond
Ω	ohm
%	percent
pF	picofarad
V	volt
W	watt

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Document History Page

Document Title: CY7C1061AV33, 16-Mbit (1M × 16) Static RAM Document Number: 38-05256				
Revision	**ECN**	**Submission Date**	**Orig. of Change**	**Description of Change**
**	113725	03/28/02	NSL	New data sheet
*A	117058	07/31/02	DFP	Removed 15-ns bin
*B	117989	08/30/02	DFP	Added 8-ns bin Changed Icc for 8, 10, 12 bins t_{power} changed from 1 µs to 1 ms. Load Cap Comment changed (for Tx line load) t_{SD} changed to 5.5 ns for the 10-ns bin Changed some 8-ns bin numbers (t_{HZ}, t_{DOE}, t_{DBE}) Removed hz<lz comments from data sheet
*C	120383	11/06/02	DFP	Final data sheet Added note 3 to “AC Test Loads and Waveforms” and note 7 to t_{pu} and t_{pd} Updated Input/Output Caps (for 48BGA only) to 8 pF/10 pF and for the 54-pin TSOP to 6/8 pF
*D	124439	2/25/03	MEG	Changed ISB1 from 100 mA to 70 mA Shaded fBGA production ordering information
*E	492137	See ECN	NXR	Corrected Block Diagram on page #1 Removed 8 ns speed bin Changed 48-Ball FBGA to 60-Ball FBGA in Pin Configuration Included Note #1 and 2 on page #2 Changed the description of I_{IX} from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Updated the Ordering Information Table
*F	508117	See ECN	NXR	Updated FBGA Pin Configuration Updated Ordering Information table
*G	877322	See ECN	VKN	Updated Ordering Information table
*H	2897049	03/22/10	KAO	Removed inactive parts from the ordering information table. Updated package diagrams. Updated links in Sales, Solutions and Legal Information.
*I	3109147	12/13/2010	KAO	Added Ordering Code Definitions under Ordering Information.
*J	3160428	02/02/11	PRAS	Updated Ordering Information: Updated part numbers. Updated to new template.
*K	3222127	04/11/2011	PRAS	Added Acronyms and Units of Measure.
*L	4363272	04/28/2014	MEMJ	Updated Switching Waveforms: Added Note 20 and referred in Figure 8. Updated Package Diagrams: spec 51-85160 – Changed revision from *A to *D. spec 51-85162 – Changed revision from *E to *F. Updated to new template. Completing Sunset Review.
*M	4578447	01/16/2015	MEMJ	Updated Functional Description: Added “For a complete list of related documentation, click here.” at the end. Updated Package Diagrams: spec 51-85160 – Changed revision from *D to *E.
*N	5738556	05/16/2017	VINI	Obsolete document. Completing Sunset Review.

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